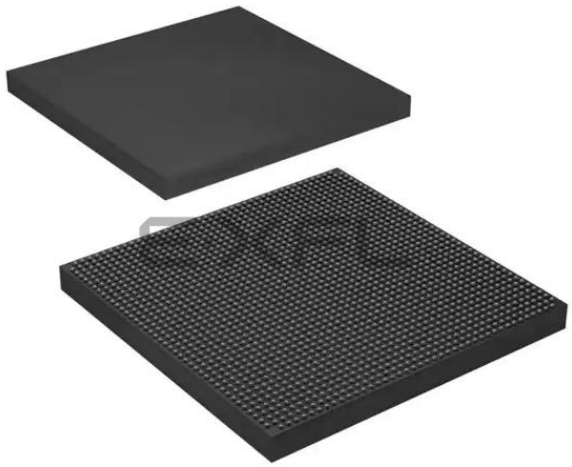

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## Understanding Embedded - FPGAs (Field Programmable Gate Array)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

## Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

| Details | |
|---|---|
| Product Status | Obsolete |
| Number of LABs/CLBs | 185000 |
| Number of Logic Elements/Cells | 490000 |
| Total RAM Bits | 41984000 |
| Number of I/O | 600 |
| Number of Gates | - |
| Voltage - Supply | 0.87V ~ 0.93V |
| Mounting Type | Surface Mount |
| Operating Temperature | 0°C ~ 85°C (TJ) |
| Package / Case | 1760-BBGA, FCBGA |
| Supplier Device Package | 1760-FCBGA (42.5x42.5) |
| Purchase URL | https://www.e-xfl.com/product-detail/intel/5sgxeb5r1f43c1n |

**Table 3. Absolute Maximum Ratings for Stratix V Devices (Part 2 of 2)**

| Symbol | Description | Minimum | Maximum | Unit |
|---|---|---|---|---|
| $V_{CCD\_FPLL}$ | PLL digital power supply | –0.5 | 1.8 | V |
| $V_{CCA\_FPLL}$ | PLL analog power supply | –0.5 | 3.4 | V |
| $V_I$ | DC input voltage | –0.5 | 3.8 | V |
| $T_J$ | Operating junction temperature | –55 | 125 | °C |
| $T_{STG}$ | Storage temperature (No bias) | –65 | 150 | °C |
| $I_{OUT}$ | DC output current per pin | –25 | 40 | mA |

Table 4 lists the absolute conditions for the transceiver power supply for Stratix V GX, GS, and GT devices.

**Table 4. Transceiver Power Supply Absolute Conditions for Stratix V GX, GS, and GT Devices**

| Symbol | Description | Devices | Minimum | Maximum | Unit |
|---|---|---|---|---|---|
| $V_{CCA\_GXBL}$ | Transceiver channel PLL power supply (left side) | GX, GS, GT | –0.5 | 3.75 | V |
| $V_{CCA\_GXBR}$ | Transceiver channel PLL power supply (right side) | GX, GS | –0.5 | 3.75 | V |
| $V_{CCA\_GTBR}$ | Transceiver channel PLL power supply (right side) | GT | –0.5 | 3.75 | V |
| $V_{CCHIP\_L}$ | Transceiver hard IP power supply (left side) | GX, GS, GT | –0.5 | 1.35 | V |
| $V_{CCHIP\_R}$ | Transceiver hard IP power supply (right side) | GX, GS, GT | –0.5 | 1.35 | V |
| $V_{CCHSSI\_L}$ | Transceiver PCS power supply (left side) | GX, GS, GT | –0.5 | 1.35 | V |
| $V_{CCHSSI\_R}$ | Transceiver PCS power supply (right side) | GX, GS, GT | –0.5 | 1.35 | V |
| $V_{CCR\_GXBL}$ | Receiver analog power supply (left side) | GX, GS, GT | –0.5 | 1.35 | V |
| $V_{CCR\_GXBR}$ | Receiver analog power supply (right side) | GX, GS, GT | –0.5 | 1.35 | V |
| $V_{CCR\_GTBR}$ | Receiver analog power supply for GT channels (right side) | GT | –0.5 | 1.35 | V |
| $V_{CCT\_GXBL}$ | Transmitter analog power supply (left side) | GX, GS, GT | –0.5 | 1.35 | V |
| $V_{CCT\_GXBR}$ | Transmitter analog power supply (right side) | GX, GS, GT | –0.5 | 1.35 | V |
| $V_{CCT\_GTBR}$ | Transmitter analog power supply for GT channels (right side) | GT | –0.5 | 1.35 | V |
| $V_{CCL\_GTBR}$ | Transmitter clock network power supply (right side) | GT | –0.5 | 1.35 | V |
| $V_{CCH\_GXBL}$ | Transmitter output buffer power supply (left side) | GX, GS, GT | –0.5 | 1.8 | V |
| $V_{CCH\_GXBR}$ | Transmitter output buffer power supply (right side) | GX, GS, GT | –0.5 | 1.8 | V |

### Maximum Allowed Overshoot and Undershoot Voltage

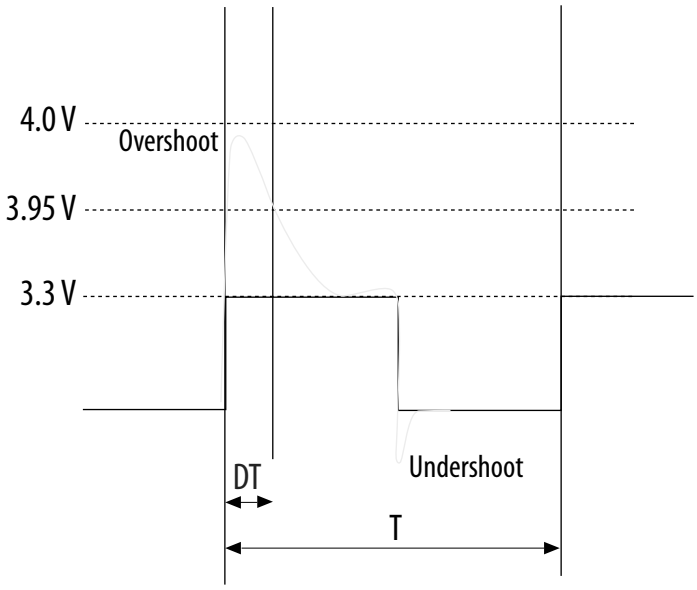
During transitions, input signals may overshoot to the voltage shown in Table 5 and undershoot to –2.0 V for input currents less than 100 mA and periods shorter than 20 ns.

Table 5 lists the maximum allowed input overshoot voltage and the duration of the overshoot voltage as a percentage of device lifetime. The maximum allowed overshoot duration is specified as a percentage of high time over the lifetime of the device. A DC signal is equivalent to 100% of the duty cycle. For example, a signal that overshoots to 3.95 V can be at 3.95 V for only ~21% over the lifetime of the device; for a device lifetime of 10 years, the overshoot duration amounts to ~2 years.

**Table 5. Maximum Allowed Overshoot During Transitions**

| Symbol | Description | Condition (V) | Overshoot Duration as % @ $T_J$ = 100°C | Unit |
|---|---|---|---|---|
| Vi (AC) | AC input voltage | 3.8 | 100 | % |
| | | 3.85 | 64 | % |
| | | 3.9 | 36 | % |
| | | 3.95 | 21 | % |
| | | 4 | 12 | % |
| | | 4.05 | 7 | % |
| | | 4.1 | 4 | % |
| | | 4.15 | 2 | % |
| | | 4.2 | 1 | % |

**Figure 1. Stratix V Device Overshoot Duration**



### I/O Pin Leakage Current

Table 9 lists the Stratix V I/O pin leakage current specifications.

**Table 9. I/O Pin Leakage Current for Stratix V Devices (1)**

| Symbol | Description | Conditions | Min | Typ | Max | Unit |
|---|---|---|---|---|---|---|
| $I_I$ | Input pin | $V_I$ = 0 V to $V_{CCIOMAX}$ | –30 | — | 30 | µA |
| $I_{OZ}$ | Tri-stated I/O pin | $V_O$ = 0 V to $V_{CCIOMAX}$ | –30 | — | 30 | µA |

**Note to Table 9:**

(1) If $V_O = V_{CCIO}$ to $V_{CCIOMax}$, 100 µA of leakage current per I/O is expected.

### Bus Hold Specifications

Table 10 lists the Stratix V device family bus hold specifications.

**Table 10. Bus Hold Parameters for Stratix V Devices**

| Parameter | Symbol | Conditions | $V_{CCIO}$ | | | | | | | | | | Unit |
|---|---|---|---|---|---|---|---|---|---|---|---|---|---|
| | | | 1.2 V | | 1.5 V | | 1.8 V | | 2.5 V | | 3.0 V | | |
| | | | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | |
| Low sustaining current | $I_{SUSL}$ | $V_{IN} > V_{IL}$ (maximum) | 22.5 | — | 25.0 | — | 30.0 | — | 50.0 | — | 70.0 | — | µA |
| High sustaining current | $I_{SUSH}$ | $V_{IN} < V_{IH}$ (minimum) | –22.5 | — | –25.0 | — | –30.0 | — | –50.0 | — | –70.0 | — | µA |
| Low overdrive current | $I_{ODL}$ | $0V < V_{IN} < V_{CCIO}$ | — | 120 | — | 160 | — | 200 | — | 300 | — | 500 | µA |
| High overdrive current | $I_{ODH}$ | $0V < V_{IN} < V_{CCIO}$ | — | –120 | — | –160 | — | –200 | — | –300 | — | –500 | µA |
| Bus-hold trip point | $V_{TRIP}$ | — | 0.45 | 0.95 | 0.50 | 1.00 | 0.68 | 1.07 | 0.70 | 1.70 | 0.80 | 2.00 | V |

### On-Chip Termination (OCT) Specifications

If you enable OCT calibration, calibration is automatically performed at power-up for I/Os connected to the calibration block. Table 11 lists the Stratix V OCT termination calibration accuracy specifications.

**Table 11. OCT Calibration Accuracy Specifications for Stratix V Devices (1) (Part 1 of 2)**

| Symbol | Description | Conditions | Calibration Accuracy | | | | Unit |
|---|---|---|---|---|---|---|---|
| | | | C1 | C2,I2 | C3,I3, I3YY | C4,I4 | |
| 25-Ω $R_S$ | Internal series termination with calibration (25-Ω setting) | $V_{CCIO}$ = 3.0, 2.5, 1.8, 1.5, 1.2 V | ±15 | ±15 | ±15 | ±15 | % |

**Table 11. OCT Calibration Accuracy Specifications for Stratix V Devices (1) (Part 2 of 2)**

| Symbol | Description | Conditions | Calibration Accuracy | | | | Unit |
|---|---|---|---|---|---|---|---|
| | | | C1 | C2,I2 | C3,I3, I3YY | C4,I4 | |
| 50-Ω $R_S$ | Internal series termination with calibration (50-Ω setting) | $V_{CCIO}$ = 3.0, 2.5, 1.8, 1.5, 1.2 V | ±15 | ±15 | ±15 | ±15 | % |
| 34-Ω and 40-Ω $R_S$ | Internal series termination with calibration (34-Ω and 40-Ω setting) | $V_{CCIO}$ = 1.5, 1.35, 1.25, 1.2 V | ±15 | ±15 | ±15 | ±15 | % |
| 48-Ω, 60-Ω, 80-Ω, and 240-Ω $R_S$ | Internal series termination with calibration (48-Ω, 60-Ω, 80-Ω, and 240-Ω setting) | $V_{CCIO}$ = 1.2 V | ±15 | ±15 | ±15 | ±15 | % |
| 50-Ω $R_T$ | Internal parallel termination with calibration (50-Ω setting) | $V_{CCIO}$ = 2.5, 1.8, 1.5, 1.2 V | –10 to +40 | –10 to +40 | –10 to +40 | –10 to +40 | % |
| 20-Ω, 30-Ω, 40-Ω,60-Ω, and 120-Ω $R_T$ | Internal parallel termination with calibration (20-Ω, 30-Ω, 40-Ω, 60-Ω, and 120-Ω setting) | $V_{CCIO}$ = 1.5, 1.35, 1.25 V | –10 to +40 | –10 to +40 | –10 to +40 | –10 to +40 | % |
| 60-Ω and 120-Ω $R_T$ | Internal parallel termination with calibration (60-Ω and 120-Ω setting) | $V_{CCIO}$ = 1.2 | –10 to +40 | –10 to +40 | –10 to +40 | –10 to +40 | % |
| 25-Ω $R_{S\_left\_shift}$ | Internal left shift series termination with calibration (25-Ω $R_{S\_left\_shift}$ setting) | $V_{CCIO}$ = 3.0, 2.5, 1.8, 1.5, 1.2 V | ±15 | ±15 | ±15 | ±15 | % |

**Note to Table 11:**

(1) OCT calibration accuracy is valid at the time of calibration only.

Table 12 lists the Stratix V OCT without calibration resistance tolerance to PVT changes.

**Table 12. OCT Without Calibration Resistance Tolerance Specifications for Stratix V Devices (Part 1 of 2)**

| Symbol | Description | Conditions | Resistance Tolerance | | | | Unit |
|---|---|---|---|---|---|---|---|
| | | | C1 | C2,I2 | C3, I3, I3YY | C4, I4 | |
| 25-Ω R, 50-Ω $R_S$ | Internal series termination without calibration (25-Ω setting) | $V_{CCIO}$ = 3.0 and 2.5 V | ±30 | ±30 | ±40 | ±40 | % |
| 25-Ω $R_S$ | Internal series termination without calibration (25-Ω setting) | $V_{CCIO}$ = 1.8 and 1.5 V | ±30 | ±30 | ±40 | ±40 | % |
| 25-Ω $R_S$ | Internal series termination without calibration (25-Ω setting) | $V_{CCIO}$ = 1.2 V | ±35 | ±35 | ±50 | ±50 | % |

**Table 12. OCT Without Calibration Resistance Tolerance Specifications for Stratix V Devices (Part 2 of 2)**

| Symbol | Description | Conditions | Resistance Tolerance | | | | Unit |
|---|---|---|---|---|---|---|---|
| | | | C1 | C2,I2 | C3, I3, I3YY | C4, I4 | |
| 50-Ω $R_S$ | Internal series termination without calibration (50-Ω setting) | $V_{CCIO}$ = 1.8 and 1.5 V | ±30 | ±30 | ±40 | ±40 | % |
| 50-Ω $R_S$ | Internal series termination without calibration (50-Ω setting) | $V_{CCIO}$ = 1.2 V | ±35 | ±35 | ±50 | ±50 | % |
| 100-Ω $R_D$ | Internal differential termination (100-Ω setting) | $V_{CCPD}$ = 2.5 V | ±25 | ±25 | ±25 | ±25 | % |

Calibration accuracy for the calibrated series and parallel OCTs are applicable at the moment of calibration. When voltage and temperature conditions change after calibration, the tolerance may change.

OCT calibration is automatically performed at power-up for OCT-enabled I/Os. Table 13 lists the OCT variation with temperature and voltage after power-up calibration. Use Table 13 to determine the OCT variation after power-up calibration and Equation 1 to determine the OCT variation without recalibration.

**Equation 1. OCT Variation Without Recalibration for Stratix V Devices** *(1), (2), (3), (4), (5), (6)*

$$R_{OCT} = R_{SCAL}\left(1 + \langle\frac{dR}{dT} \times \Delta T\rangle \pm \langle\frac{dR}{dV} \times \Delta V\rangle\right)$$

**Notes to Equation 1:**

(1) The $R_{OCT}$ value shows the range of OCT resistance with the variation of temperature and $V_{CCIO}$.
(2) $R_{SCAL}$ is the OCT resistance value at power-up.
(3) $\Delta T$ is the variation of temperature with respect to the temperature at power-up.
(4) $\Delta V$ is the variation of voltage with respect to the $V_{CCIO}$ at power-up.
(5) dR/dT is the percentage change of $R_{SCAL}$ with temperature.
(6) dR/dV is the percentage change of $R_{SCAL}$ with voltage.

Table 13 lists the on-chip termination variation after power-up calibration.

**Table 13. OCT Variation after Power-Up Calibration for Stratix V Devices (Part 1 of 2)** *(1)*

| Symbol | Description | $V_{CCIO}$ (V) | Typical | Unit |
|---|---|---|---|---|
| dR/dV | OCT variation with voltage without recalibration | 3.0 | 0.0297 | %/mV |
| | | 2.5 | 0.0344 | |
| | | 1.8 | 0.0499 | |
| | | 1.5 | 0.0744 | |
| | | 1.2 | 0.1241 | |

# Switching Characteristics

This section provides performance characteristics of the Stratix V core and periphery blocks.

These characteristics can be designated as Preliminary or Final.

- Preliminary characteristics are created using simulation results, process data, and other known parameters. The title of these tables show the designation as "Preliminary."
- Final numbers are based on actual silicon characterization and testing. The numbers reflect the actual performance of the device under worst-case silicon process, voltage, and junction temperature conditions. There are no designations on finalized tables.

## Transceiver Performance Specifications

This section describes transceiver performance specifications.

Table 23 lists the Stratix V GX and GS transceiver specifications.

**Table 23. Transceiver Specifications for Stratix V GX and GS Devices (1) (Part 1 of 7)**

| Symbol/ Description | Conditions | Transceiver Speed Grade 1 | | | Transceiver Speed Grade 2 | | | Transceiver Speed Grade 3 | | | Unit |
|---|---|---|---|---|---|---|---|---|---|---|---|
| | | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max | |
| **Reference Clock** | | | | | | | | | | | |
| Supported I/O Standards | Dedicated reference clock pin | 1.2-V PCML, 1.4-V PCML, 1.5-V PCML, 2.5-V PCML, Differential LVPECL, LVDS, and HCSL | | | | | | | | | |
| | RX reference clock pin | 1.4-V PCML, 1.5-V PCML, 2.5-V PCML, LVPECL, and LVDS | | | | | | | | | |
| Input Reference Clock Frequency (CMU PLL) (8) | — | 40 | — | 710 | 40 | — | 710 | 40 | — | 710 | MHz |
| Input Reference Clock Frequency (ATX PLL) (8) | — | 100 | — | 710 | 100 | — | 710 | 100 | — | 710 | MHz |
| Rise time | Measure at ±60 mV of differential signal (26) | — | — | 400 | — | — | 400 | — | — | 400 | ps |
| Fall time | Measure at ±60 mV of differential signal (26) | — | — | 400 | — | — | 400 | — | — | 400 | |
| Duty cycle | — | 45 | — | 55 | 45 | — | 55 | 45 | — | 55 | % |
| Spread-spectrum modulating clock frequency | PCI Express® (PCIe®) | 30 | — | 33 | 30 | — | 33 | 30 | — | 33 | kHz |

**Table 23. Transceiver Specifications for Stratix V GX and GS Devices (1) (Part 2 of 7)**

| Symbol/ Description | Conditions | Transceiver Speed Grade 1 | | | Transceiver Speed Grade 2 | | | Transceiver Speed Grade 3 | | | Unit |
|---|---|---|---|---|---|---|---|---|---|---|---|
| | | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max | |
| Spread-spectrum downspread | PCIe | — | 0 to –0.5 | — | — | 0 to –0.5 | — | — | 0 to –0.5 | — | % |
| On-chip termination resistors (21) | — | — | 100 | — | — | 100 | — | — | 100 | — | Ω |
| Absolute $V_{MAX}$ (5) | Dedicated reference clock pin | — | — | 1.6 | — | — | 1.6 | — | — | 1.6 | V |
| | RX reference clock pin | — | — | 1.2 | — | — | 1.2 | — | — | 1.2 | |
| Absolute $V_{MIN}$ | — | –0.4 | — | — | –0.4 | — | — | –0.4 | — | — | V |
| Peak-to-peak differential input voltage | — | 200 | — | 1600 | 200 | — | 1600 | 200 | — | 1600 | mV |
| $V_{ICM}$ (AC coupled) (3) | Dedicated reference clock pin | 1050/1000/900/850 (2) | | | 1050/1000/900/850 (2) | | | 1050/1000/900/850 (2) | | | mV |
| | RX reference clock pin | 1.0/0.9/0.85 (4) | | | 1.0/0.9/0.85 (4) | | | 1.0/0.9/0.85 (4) | | | V |
| $V_{ICM}$ (DC coupled) | HCSL I/O standard for PCIe reference clock | 250 | — | 550 | 250 | — | 550 | 250 | — | 550 | mV |
| Transmitter REFCLK Phase Noise (622 MHz) (20) | 100 Hz | — | — | -70 | — | — | -70 | — | — | -70 | dBc/Hz |
| | 1 kHz | — | — | -90 | — | — | -90 | — | — | -90 | dBc/Hz |
| | 10 kHz | — | — | -100 | — | — | -100 | — | — | -100 | dBc/Hz |
| | 100 kHz | — | — | -110 | — | — | -110 | — | — | -110 | dBc/Hz |
| | ≥1 MHz | — | — | -120 | — | — | -120 | — | — | -120 | dBc/Hz |
| Transmitter REFCLK Phase Jitter (100 MHz) (17) | 10 kHz to 1.5 MHz (PCIe) | — | — | 3 | — | — | 3 | — | — | 3 | ps (rms) |
| $R_{REF}$ (19) | — | — | 1800 ±1% | — | — | 1800 ±1% | — | — | 1800 ±1% | — | Ω |
| **Transceiver Clocks** | | | | | | | | | | | |
| `fixedclk` clock frequency | PCIe Receiver Detect | — | 100 or 125 | — | — | 100 or 125 | — | — | 100 or 125 | — | MHz |

**Table 23. Transceiver Specifications for Stratix V GX and GS Devices (1) (Part 5 of 7)**

| Symbol/ Description | Conditions | Transceiver Speed Grade 1 | | | Transceiver Speed Grade 2 | | | Transceiver Speed Grade 3 | | | Unit |
|---|---|---|---|---|---|---|---|---|---|---|---|
| | | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max | |
| Programmable DC gain | DC Gain Setting = 0 | — | 0 | — | — | 0 | — | — | 0 | — | dB |
| | DC Gain Setting = 1 | — | 2 | — | — | 2 | — | — | 2 | — | dB |
| | DC Gain Setting = 2 | — | 4 | — | — | 4 | — | — | 4 | — | dB |
| | DC Gain Setting = 3 | — | 6 | — | — | 6 | — | — | 6 | — | dB |
| | DC Gain Setting = 4 | — | 8 | — | — | 8 | — | — | 8 | — | dB |
| **Transmitter** | | | | | | | | | | | |
| Supported I/O Standards | — | 1.4-V and 1.5-V PCML | | | | | | | | | |
| Data rate (Standard PCS) | — | 600 | — | 12200 | 600 | — | 12200 | 600 | — | 8500/ 10312.5 (24) | Mbps |
| Data rate (10G PCS) | — | 600 | — | 14100 | 600 | — | 12500 | 600 | — | 8500/ 10312.5 (24) | Mbps |
| Differential on-chip termination resistors | 85-Ω setting | — | 85 ± 20% | — | — | 85 ± 20% | — | — | 85 ± 20% | — | Ω |
| | 100-Ω setting | — | 100 ± 20% | — | — | 100 ± 20% | — | — | 100 ± 20% | — | Ω |
| | 120-Ω setting | — | 120 ± 20% | — | — | 120 ± 20% | — | — | 120 ± 20% | — | Ω |
| | 150-Ω setting | — | 150 ± 20% | — | — | 150 ± 20% | — | — | 150 ± 20% | — | Ω |
| $V_{OCM}$ (AC coupled) | 0.65-V setting | — | 650 | — | — | 650 | — | — | 650 | — | mV |
| $V_{OCM}$ (DC coupled) | — | — | 650 | — | — | 650 | — | — | 650 | — | mV |
| Rise time (7) | 20% to 80% | 30 | — | 160 | 30 | — | 160 | 30 | — | 160 | ps |
| Fall time (7) | 80% to 20% | 30 | — | 160 | 30 | — | 160 | 30 | — | 160 | ps |
| Intra-differential pair skew | Tx $V_{CM}$ = 0.5 V and slew rate of 15 ps | — | — | 15 | — | — | 15 | — | — | 15 | ps |
| Intra-transceiver block transmitter channel-to-channel skew | x6 PMA bonded mode | — | — | 120 | — | — | 120 | — | — | 120 | ps |

Table 24 shows the maximum transmitter data rate for the clock network.

**Table 24. Clock Network Maximum Data Rate Transmitter Specifications** *(1)*

| Clock Network | ATX PLL | | | CMU PLL *(2)* | | | fPLL | | |
|---|---|---|---|---|---|---|---|---|---|
| | Non-bonded Mode (Gbps) | Bonded Mode (Gbps) | Channel Span | Non-bonded Mode (Gbps) | Bonded Mode (Gbps) | Channel Span | Non-bonded Mode (Gbps) | Bonded Mode (Gbps) | Channel Span |
| x1 *(3)* | 14.1 | — | 6 | 12.5 | — | 6 | 3.125 | — | 3 |
| x6 *(3)* | — | 14.1 | 6 | — | 12.5 | 6 | — | 3.125 | 6 |
| x6 PLL Feedback *(4)* | — | 14.1 | Side-wide | — | 12.5 | Side-wide | — | — | — |
| xN (PCIe) | — | 8.0 | 8 | — | 5.0 | 8 | — | — | — |
| xN (Native PHY IP) | 8.0 | 8.0 | Up to 13 channels above and below PLL | 7.99 | 7.99 | Up to 13 channels above and below PLL | 3.125 | 3.125 | Up to 13 channels above and below PLL |
| | — | 8.01 to 9.8304 | Up to 7 channels above and below PLL | | | | | | |

**Notes to Table 24:**

(1) Valid data rates below the maximum specified in this table depend on the reference clock frequency and the PLL counter settings. Check the MegaWizard message during the PHY IP instantiation.

(2) ATX PLL is recommended at 8 Gbps and above data rates for improved jitter performance.

(3) Channel span is within a transceiver bank.

(4) Side-wide channel bonding is allowed up to the maximum supported by the PHY IP.

**Table 28. Transceiver Specifications for Stratix V GT Devices (Part 1 of 5) (1)**

| Symbol/ Description | Conditions | Transceiver Speed Grade 2 | | | Transceiver Speed Grade 3 | | | Unit |
|---|---|---|---|---|---|---|---|---|
| | | Min | Typ | Max | Min | Typ | Max | |
| **Reference Clock** | | | | | | | | |
| Supported I/O Standards | Dedicated reference clock pin | 1.2-V PCML, 1.4-V PCML, 1.5-V PCML, 2.5-V PCML, Differential LVPECL, LVDS, and HCSL | | | | | | |
| | RX reference clock pin | 1.4-V PCML, 1.5-V PCML, 2.5-V PCML, LVPECL, and LVDS | | | | | | |
| Input Reference Clock Frequency (CMU PLL) (6) | — | 40 | — | 710 | 40 | — | 710 | MHz |
| Input Reference Clock Frequency (ATX PLL) (6) | — | 100 | — | 710 | 100 | — | 710 | MHz |
| Rise time | 20% to 80% | — | — | 400 | — | — | 400 | ps |
| Fall time | 80% to 20% | — | — | 400 | — | — | 400 | |
| Duty cycle | — | 45 | — | 55 | 45 | — | 55 | % |
| Spread-spectrum modulating clock frequency | PCI Express (PCIe) | 30 | — | 33 | 30 | — | 33 | kHz |
| Spread-spectrum downspread | PCIe | — | 0 to –0.5 | — | — | 0 to –0.5 | — | % |
| On-chip termination resistors (19) | — | — | 100 | — | — | 100 | — | Ω |
| Absolute $V_{MAX}$ (3) | Dedicated reference clock pin | — | — | 1.6 | — | — | 1.6 | V |
| | RX reference clock pin | — | — | 1.2 | — | — | 1.2 | |
| Absolute $V_{MIN}$ | — | -0.4 | — | — | -0.4 | — | — | V |
| Peak-to-peak differential input voltage | — | 200 | — | 1600 | 200 | — | 1600 | mV |
| $V_{ICM}$ (AC coupled) | Dedicated reference clock pin | 1050/1000 (2) | | | 1050/1000 (2) | | | mV |
| | RX reference clock pin | 1.0/0.9/0.85 (22) | | | 1.0/0.9/0.85 (22) | | | V |
| $V_{ICM}$ (DC coupled) | HCSL I/O standard for PCIe reference clock | 250 | — | 550 | 250 | — | 550 | mV |

**Table 28. Transceiver Specifications for Stratix V GT Devices (Part 4 of 5) (1)**

| Symbol/ Description | Conditions | Transceiver Speed Grade 2 | | | Transceiver Speed Grade 3 | | | Unit |
|---|---|---|---|---|---|---|---|---|
| | | Min | Typ | Max | Min | Typ | Max | |
| Data rate | GT channels | 19,600 | — | 28,050 | 19,600 | — | 25,780 | Mbps |
| Differential on-chip termination resistors | GT channels | — | 100 | — | — | 100 | — | Ω |
| | GX channels | (8) | | | | | | |
| $V_{OCM}$ (AC coupled) | GT channels | — | 500 | — | — | 500 | — | mV |
| | GX channels | (8) | | | | | | |
| Rise/Fall time | GT channels | — | 15 | — | — | 15 | — | ps |
| | GX channels | (8) | | | | | | |
| Intra-differential pair skew | GX channels | (8) | | | | | | |
| Intra-transceiver block transmitter channel-to-channel skew | GX channels | (8) | | | | | | |
| Inter-transceiver block transmitter channel-to-channel skew | GX channels | (8) | | | | | | |
| **CMU PLL** | | | | | | | | |
| Supported Data Range | — | 600 | — | 12500 | 600 | — | 8500 | Mbps |
| $t_{pll\_powerdown}$ (13) | — | 1 | — | — | 1 | — | — | µs |
| $t_{pll\_lock}$ (14) | — | — | — | 10 | — | — | 10 | µs |
| **ATX PLL** | | | | | | | | |
| Supported Data Rate Range for GX Channels | VCO post-divider L=2 | 8000 | — | 12500 | 8000 | — | 8500 | Mbps |
| | L=4 | 4000 | — | 6600 | 4000 | — | 6600 | Mbps |
| | L=8 | 2000 | — | 3300 | 2000 | — | 3300 | Mbps |
| | L=8, Local/Central Clock Divider =2 | 1000 | — | 1762.5 | 1000 | — | 1762.5 | Mbps |
| Supported Data Rate Range for GT Channels | VCO post-divider L=2 | 9800 | — | 14025 | 9800 | — | 12890 | Mbps |
| $t_{pll\_powerdown}$ (13) | — | 1 | — | — | 1 | — | — | µs |
| $t_{pll\_lock}$ (14) | — | — | — | 10 | — | — | 10 | µs |
| **fPLL** | | | | | | | | |
| Supported Data Range | — | 600 | — | 3250/ 3.125 (23) | 600 | — | 3250/ 3.125 (23) | Mbps |
| $t_{pll\_powerdown}$ (13) | — | 1 | — | — | 1 | — | — | µs |

**Table 36. High-Speed I/O Specifications for Stratix V Devices (1), (2) (Part 3 of 4)**

| Symbol | Conditions | C1 | | | C2, C2L, I2, I2L | | | C3, I3, I3L, I3YY | | | C4,I4 | | | Unit |
|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|
| | | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max | |
| $t_{DUTY}$ | Transmitter output clock duty cycle for both True and Emulated Differential I/O Standards | 45 | 50 | 55 | 45 | 50 | 55 | 45 | 50 | 55 | 45 | 50 | 55 | % |
| $t_{RISE}$ & $t_{FALL}$ | True Differential I/O Standards | — | — | 160 | — | — | 160 | — | — | 200 | — | — | 200 | ps |
| | Emulated Differential I/O Standards with three external output resistor networks | — | — | 250 | — | — | 250 | — | — | 250 | — | — | 300 | ps |
| TCCS | True Differential I/O Standards | — | — | 150 | — | — | 150 | — | — | 150 | — | — | 150 | ps |
| | Emulated Differential I/O Standards | — | — | 300 | — | — | 300 | — | — | 300 | — | — | 300 | ps |
| **Receiver** | | | | | | | | | | | | | | |
| True Differential I/O Standards - $f_{HSDRDPA}$ (data rate) | SERDES factor J = 3 to 10 (11), (12), (13), (14), (15), (16) | 150 | — | 1434 | 150 | — | 1434 | 150 | — | 1250 | 150 | — | 1050 | Mbps |
| | SERDES factor J ≥ 4 LVDS RX with DPA (12), (14), (15), (16) | 150 | — | 1600 | 150 | — | 1600 | 150 | — | 1600 | 150 | — | 1250 | Mbps |
| | SERDES factor J = 2, uses DDR Registers | (6) | — | (7) | (6) | — | (7) | (6) | — | (7) | (6) | — | (7) | Mbps |
| | SERDES factor J = 1, uses SDR Register | (6) | — | (7) | (6) | — | (7) | (6) | — | (7) | (6) | — | (7) | Mbps |

Figure 7 shows the dynamic phase alignment (DPA) lock time specifications with the DPA PLL calibration option enabled.

**Figure 7. DPA Lock Time Specification with DPA PLL Calibration Enabled**

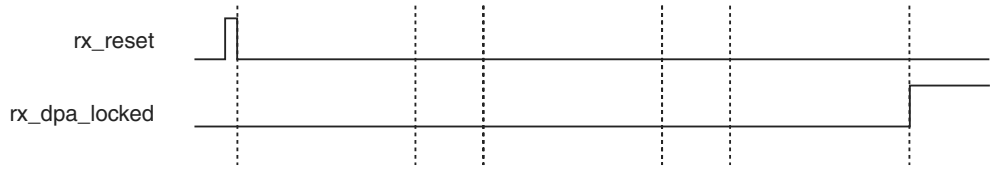



Table 37 lists the DPA lock time specifications for Stratix V devices.

**Table 37. DPA Lock Time Specifications for Stratix V GX Devices Only** *(1), (2), (3)*

| Standard | Training Pattern | Number of Data Transitions in One Repetition of the Training Pattern | Number of Repetitions per 256 Data Transitions *(4)* | Maximum |
|---|---|---|---|---|
| SPI-4 | 00000000001111111111 | 2 | 128 | 640 data transitions |
| Parallel Rapid I/O | 00001111 | 2 | 128 | 640 data transitions |
| | 10010000 | 4 | 64 | 640 data transitions |
| Miscellaneous | 10101010 | 8 | 32 | 640 data transitions |
| | 01010101 | 8 | 32 | 640 data transitions |

**Notes to Table 37:**

(1) The DPA lock time is for one channel.
(2) One data transition is defined as a 0-to-1 or 1-to-0 transition.
(3) The DPA lock time stated in this table applies to both commercial and industrial grade.
(4) This is the number of repetitions for the stated training pattern to achieve the 256 data transitions.

Figure 8 shows the **LVDS** soft-clock data recovery (CDR)/DPA sinusoidal jitter tolerance specification for a data rate ≥ 1.25 Gbps. Table 38 lists the **LVDS** soft-CDR/DPA sinusoidal jitter tolerance specification for a data rate ≥ 1.25 Gbps.

**Figure 8. LVDS Soft-CDR/DPA Sinusoidal Jitter Tolerance Specification for a Data Rate ≥ 1.25 Gbps**

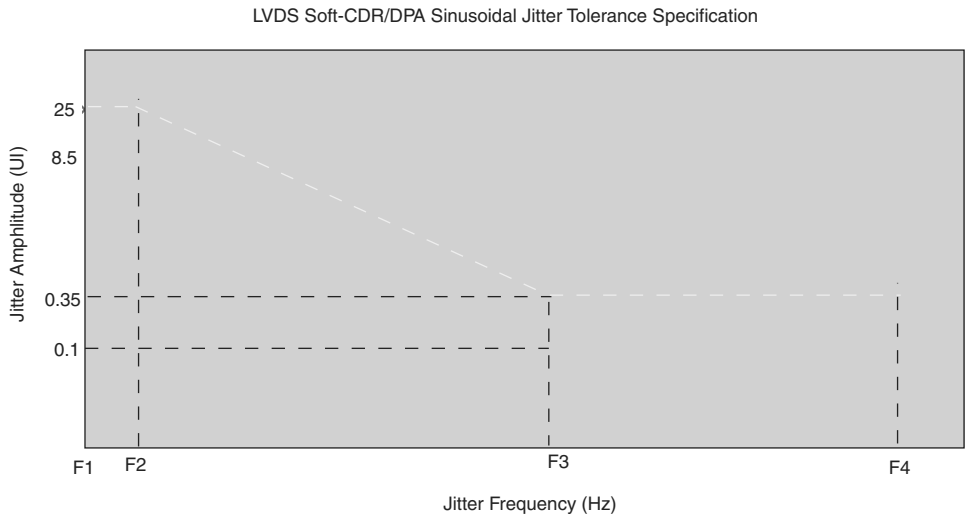
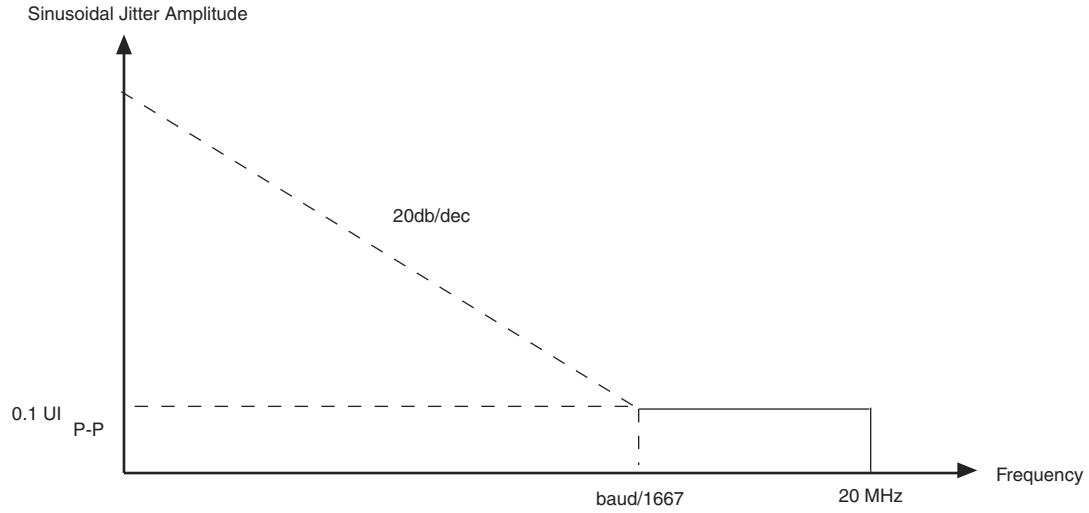


**Table 38. LVDS Soft-CDR/DPA Sinusoidal Jitter Mask Values for a Data Rate ≥ 1.25 Gbps**

| Jitter Frequency (Hz) | | Sinusoidal Jitter (UI) |
|---|---|---|
| F1 | 10,000 | 25.000 |
| F2 | 17,565 | 25.000 |
| F3 | 1,493,000 | 0.350 |
| F4 | 50,000,000 | 0.350 |

Figure 9 shows the **LVDS** soft-CDR/DPA sinusoidal jitter tolerance specification for a data rate < 1.25 Gbps.

**Figure 9. LVDS Soft-CDR/DPA Sinusoidal Jitter Tolerance Specification for a Data Rate < 1.25 Gbps**




## DLL Range, DQS Logic Block, and Memory Output Clock Jitter Specifications

Table 39 lists the DLL range specification for Stratix V devices. The DLL is always in 8-tap mode in Stratix V devices.

**Table 39. DLL Range Specifications for Stratix V Devices (1)**

| C1 | C2, C2L, I2, I2L | C3, I3, I3L, I3YY | C4,I4 | Unit |
|---|---|---|---|---|
| 300-933 | 300-933 | 300-890 | 300-890 | MHz |

**Note to Table 39:**

(1) Stratix V devices support memory interface frequencies lower than 300 MHz, although the reference clock that feeds the DLL must be at least 300 MHz. To support interfaces below 300 MHz, multiply the reference clock feeding the DLL to ensure the frequency is within the supported range of the DLL.

Table 40 lists the DQS phase offset delay per stage for Stratix V devices.

**Table 40. DQS Phase Offset Delay Per Setting for Stratix V Devices (1), (2) (Part 1 of 2)**

| Speed Grade | Min | Max | Unit |
|---|---|---|---|
| C1 | 8 | 14 | ps |
| C2, C2L, I2, I2L | 8 | 14 | ps |
| C3,I3, I3L, I3YY | 8 | 15 | ps |

## Active Serial Configuration Timing

Table 52 lists the DCLK frequency specification in the AS configuration scheme.

**Table 52. DCLK Frequency Specification in the AS Configuration Scheme (1), (2)**

| Minimum | Typical | Maximum | Unit |
|---|---|---|---|
| 5.3 | 7.9 | 12.5 | MHz |
| 10.6 | 15.7 | 25.0 | MHz |
| 21.3 | 31.4 | 50.0 | MHz |
| 42.6 | 62.9 | 100.0 | MHz |

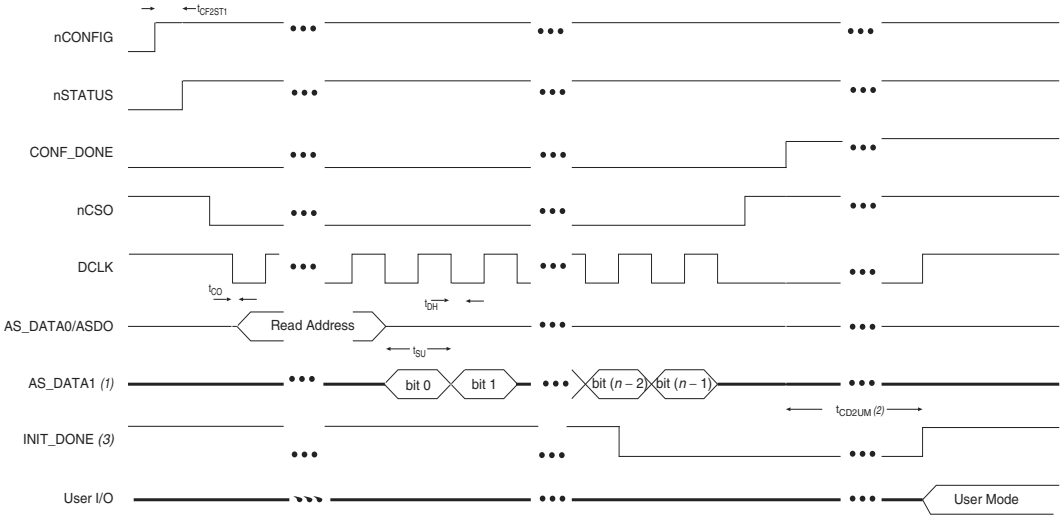
**Notes to Table 52:**

(1) This applies to the DCLK frequency specification when using the internal oscillator as the configuration clock source.

(2) The AS multi-device configuration scheme does not support DCLK frequency of 100 MHz.

Figure 14 shows the single-device configuration setup for an AS ×1 mode.

**Figure 14. AS Configuration Timing**




**Notes to Figure 14:**

(1) If you are using AS ×4 mode, this signal represents the AS_DATA[3..0] and EPCQ sends in 4-bits of data for each DCLK cycle.

(2) The initialization clock can be from internal oscillator or CLKUSR pin.

(3) After the option bit to enable the INIT_DONE pin is configured into the device, the INIT_DONE goes low.

Table 53 lists the timing parameters for AS ×1 and AS ×4 configurations in Stratix V devices.

**Table 53. AS Timing Parameters for AS ×1 and AS ×4 Configurations in Stratix V Devices (1), (2) (Part 1 of 2)**

| Symbol | Parameter | Minimum | Maximum | Units |
|---|---|---|---|---|
| $t_{CO}$ | DCLK falling edge to AS_DATA0/ASDO output | — | 2 | ns |
| $t_{SU}$ | Data setup time before falling edge on DCLK | 1.5 | — | ns |
| $t_{H}$ | Data hold time after falling edge on DCLK | 0 | — | ns |

**Table 53. AS Timing Parameters for AS ×1 and AS ×4 Configurations in Stratix V Devices (1), (2) (Part 2 of 2)**

| Symbol | Parameter | Minimum | Maximum | Units |
|---|---|---|---|---|
| $t_{CD2UM}$ | CONF_DONE high to user mode (3) | 175 | 437 | µs |
| $t_{CD2CU}$ | CONF_DONE high to CLKUSR enabled | 4 × maximum DCLK period | — | — |
| $t_{CD2UMC}$ | CONF_DONE high to user mode with CLKUSR option on | $t_{CD2CU}$ + (8576 × CLKUSR period) | — | — |

**Notes to Table 53:**

(1) The minimum and maximum numbers apply only if you choose the internal oscillator as the clock source for initializing the device.

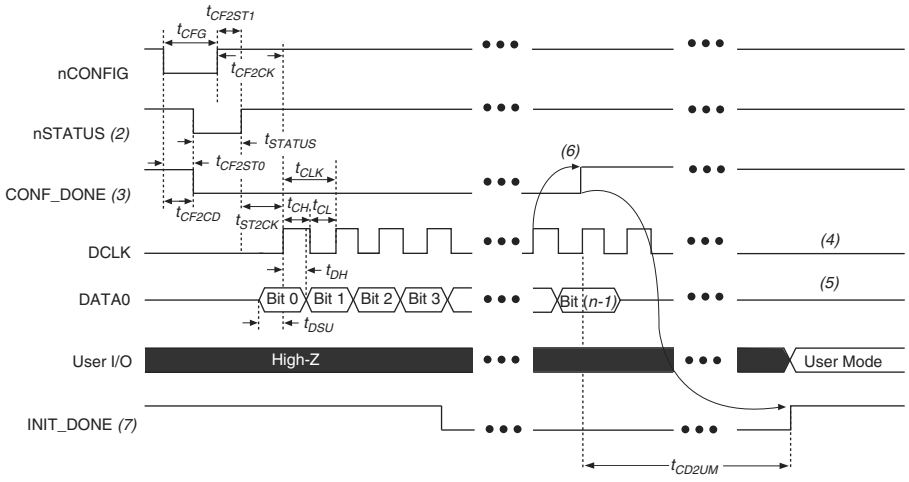
(2) $t_{CF2CD}$, $t_{CF2ST0}$, $t_{CFG}$, $t_{STATUS}$, and $t_{CF2ST1}$ timing parameters are identical to the timing parameters for PS mode listed in Table 54 on page 63.

(3) To enable the CLKUSR pin as the initialization clock source and to obtain the maximum frequency specification on this pin, refer to the Initialization section of the "Configuration, Design Security, and Remote System Upgrades in Stratix V Devices" chapter.

## Passive Serial Configuration Timing

Figure 15 shows the timing waveform for a passive serial (PS) configuration when using a MAX II device, MAX V device, or microprocessor as an external host.

**Figure 15. PS Configuration Timing Waveform (1)**




**Notes to Figure 15:**

(1) The beginning of this waveform shows the device in user mode. In user mode, nCONFIG, nSTATUS, and CONF_DONE are at logic high levels. When nCONFIG is pulled low, a reconfiguration cycle begins.

(2) After power-up, the Stratix V device holds nSTATUS low for the time of the POR delay.

(3) After power-up, before and during configuration, CONF_DONE is low.

(4) Do not leave DCLK floating after configuration. You can drive it high or low, whichever is more convenient.

(5) DATA0 is available as a user I/O pin after configuration. The state of this pin depends on the dual-purpose pin settings in the **Device and Pins Option**.

(6) To ensure a successful configuration, send the entire configuration data to the Stratix V device. CONF_DONE is released high after the Stratix V device receives all the configuration data successfully. After CONF_DONE goes high, send two additional falling edges on DCLK to begin initialization and enter user mode.

(7) After the option bit to enable the INIT_DONE pin is configured into the device, the INIT_DONE goes low.

## Remote System Upgrades

Table 56 lists the timing parameter specifications for the remote system upgrade circuitry.

**Table 56. Remote System Upgrade Circuitry Timing Specifications**

| Parameter | Minimum | Maximum | Unit |
|---|---|---|---|
| $t_{RU\_nCONFIG}$ (1) | 250 | — | ns |
| $t_{RU\_nRSTIMER}$ (2) | 250 | — | ns |

**Notes to Table 56:**

(1) This is equivalent to strobing the reconfiguration input of the ALTREMOTE_UPDATE megafunction high for the minimum timing specification. For more information, refer to the Remote System Upgrade State Machine section of the "Configuration, Design Security, and Remote System Upgrades in Stratix V Devices" chapter.

(2) This is equivalent to strobing the reset_timer input of the ALTREMOTE_UPDATE megafunction high for the minimum timing specification. For more information, refer to the User Watchdog Timer section of the "Configuration, Design Security, and Remote System Upgrades in Stratix V Devices" chapter.

## User Watchdog Internal Circuitry Timing Specification

Table 57 lists the operating range of the 12.5-MHz internal oscillator.

**Table 57. 12.5-MHz Internal Oscillator Specifications**

| Minimum | Typical | Maximum | Units |
|---|---|---|---|
| 5.3 | 7.9 | 12.5 | MHz |

# I/O Timing

Altera offers two ways to determine I/O timing—the Excel-based I/O Timing and the Quartus II Timing Analyzer.

Excel-based I/O timing provides pin timing performance for each device density and speed grade. The data is typically used prior to designing the FPGA to get an estimate of the timing budget as part of the link timing analysis. The Quartus II Timing Analyzer provides a more accurate and precise I/O timing data based on the specifics of the design after you complete place-and-route.

You can download the Excel-based I/O Timing spreadsheet from the Stratix V Devices Documentation web page.

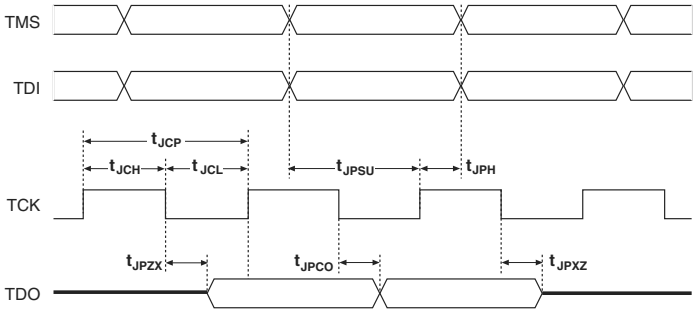
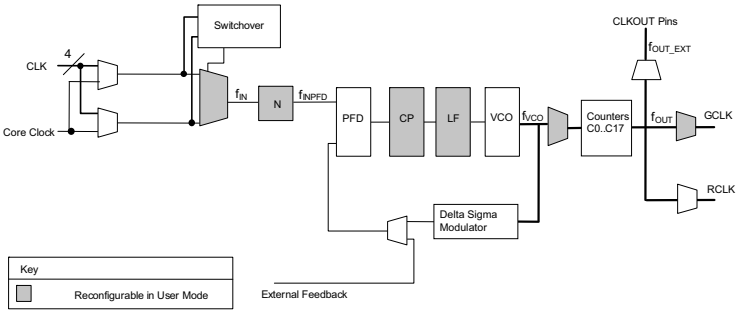
## Programmable IOE Delay

Table 58 lists the Stratix V IOE programmable delay settings.

**Table 58. IOE Programmable Delay for Stratix V Devices (Part 1 of 2)**

| Parameter (1) | Available Settings | Min Offset (2) | Fast Model | | Slow Model | | | | | | | |
|---|---|---|---|---|---|---|---|---|---|---|---|---|
| | | | Industrial | Commercial | C1 | C2 | C3 | C4 | I2 | I3, I3YY | I4 | Unit |
| D1 | 64 | 0 | 0.464 | 0.493 | 0.838 | 0.838 | 0.924 | 1.011 | 0.844 | 0.921 | 1.006 | ns |
| D2 | 32 | 0 | 0.230 | 0.244 | 0.415 | 0.415 | 0.459 | 0.503 | 0.417 | 0.456 | 0.500 | ns |

**Table 60. Glossary (Part 2 of 4)**

| Letter | Subject | Definitions |
|---|---|---|
| G<br>H<br>I | — | — |
| J | J | High-speed I/O block—Deserialization factor (width of parallel data bus). |
| J | JTAG Timing Specifications | JTAG Timing Specifications:<br>  <br> |
| K<br>L<br>M<br>N<br>O | — | — |
| P | **PLL Specifications** | **Diagram of PLL Specifications** *(1)*<br>  <br><br>**Note:**<br>(1) `Core Clock` can only be fed by dedicated clock input pins or PLL outputs. |
| Q | — | — |
| R | $R_L$ | Receiver differential input discrete resistor (external to the Stratix V device). |

# Document Revision History

Table 61 lists the revision history for this chapter.

**Table 61. Document Revision History (Part 1 of 3)**

| Date | Version | Changes |
|---|---|---|
| June 2018 | 3.9 | ■ Added the “Stratix V Device Overshoot Duration” figure. |
| April 2017 | 3.8 | ■ Added a footnote to the “High-Speed I/O Specifications for Stratix V Devices” table.<br>■ Changed the minimum value for $t_{CD2UMC}$ in the “PS Timing Parameters for Stratix V Devices” table.<br>■ Changed the condition for 100-Ω $R_D$ in the “OCT Without Calibration Resistance Tolerance Specifications for Stratix V Devices” table.<br>■ Changed the minimum value for $t_{CD2UMC}$ in the “AS Timing Parameters for AS ´1 and AS ´4 Configurations in Stratix V Devices” table<br>■ Changed the minimum value for $t_{CD2UMC}$ in the “FPP Timing Parameters for Stratix V Devices When the DCLK-to-DATA[] Ratio is >1” table.<br>■ Changed the minimum value for $t_{CD2UMC}$ in the “FPP Timing Parameters for Stratix V Devices When the DCLK-to-DATA[] Ratio is >1” table.<br>■ Changed the minimum number of clock cycles value in the “Initialization Clock Source Option and the Maximum Frequency” table. |
| June 2016 | 3.7 | ■ Added the $V_{ID}$ minimum specification for LVPECL in the “Differential I/O Standard Specifications for Stratix V Devices” table<br>■ Added the $I_{OUT}$ specification to the “Absolute Maximum Ratings for Stratix V Devices” table. |
| December 2015 | 3.6 | ■ Added a footnote to the “High-Speed I/O Specifications for Stratix V Devices” table. |
| December 2015 | 3.5 | ■ Changed the transmitter, receiver, and ATX PLL data rate specifications in the “Transceiver Specifications for Stratix V GX and GS Devices” table.<br>■ Changed the configuration .rbf sizes in the “Uncompressed .rbf Sizes for Stratix V Devices” table. |
| July 2015 | 3.4 | ■ Changed the data rate specification for transceiver speed grade 3 in the following tables:<br>  ■ “Transceiver Specifications for Stratix V GX and GS Devices”<br>  ■ “Stratix V Standard PCS Approximate Maximum Date Rate”<br>  ■ “Stratix V 10G PCS Approximate Maximum Data Rate”<br>■ Changed the conditions for reference clock rise and fall time, and added a note to the “Transceiver Specifications for Stratix V GX and GS Devices” table.<br>■ Added a note to the “Minimum differential eye opening at receiver serial input pins” specification in the “Transceiver Specifications for Stratix V GX and GS Devices” table.<br>■ Changed the $t_{CO}$ maximum value in the “AS Timing Parameters for AS ´1 and AS ´4 Configurations in Stratix V Devices” table.<br>■ Removed the CDR ppm tolerance specification from the “Transceiver Specifications for Stratix V GX and GS Devices” table. |